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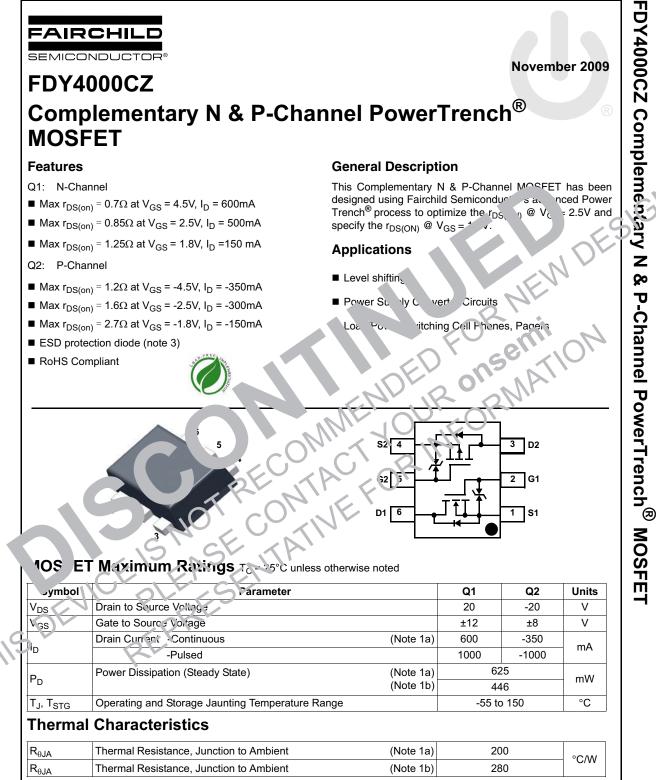
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Please note. As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild guestions@onsemi.com.

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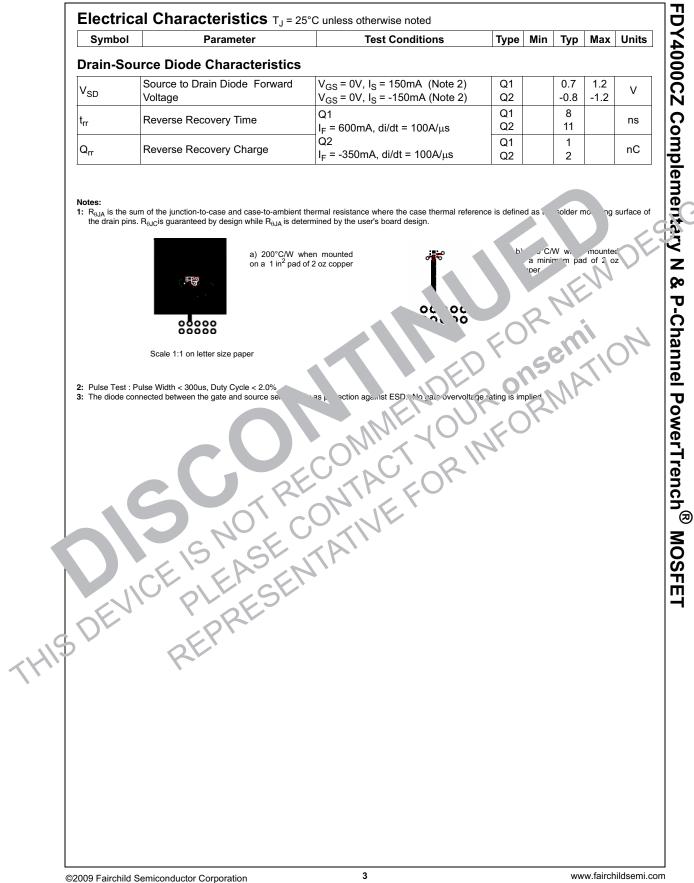


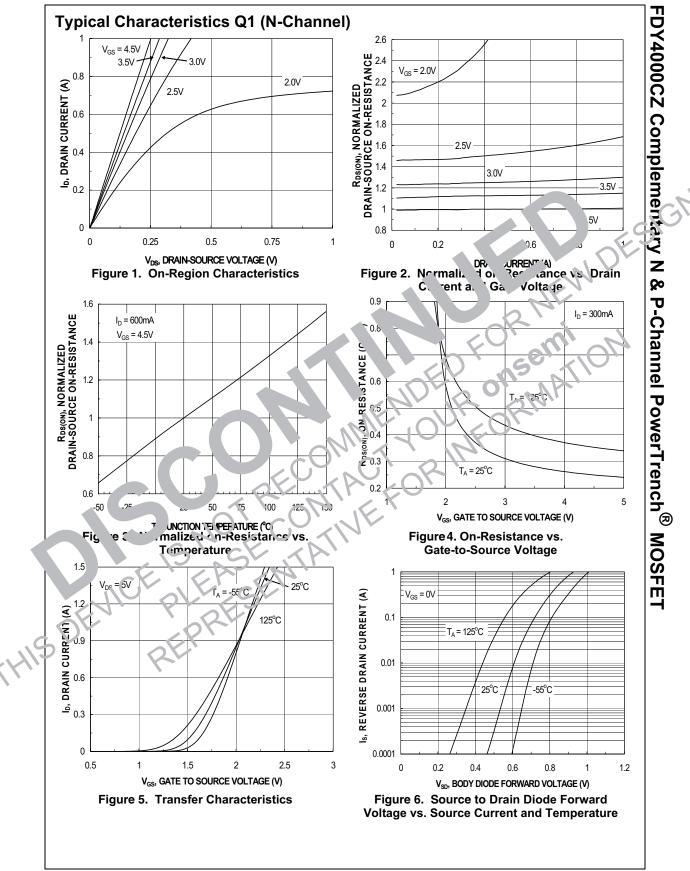
Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity	
E	FDY4000CZ	SC89-6	7"	8mm	3000units	

Symbol	Parameter	Test Conditions	Туре	Min	Тур	Max	Unit
Off Chara	acteristics						
B _{VDSS}	Drain to Source Breakdown Volt-	$I_{\rm D} = 250 \mu A, V_{\rm GS} = 0V$	Q1	20			V
ΔB _{VDSS}	age Breakdown Voltage Temperature	$I_D = -250\mu A$, $V_{GS} = 0V$ $I_D = 250\mu A$, referenced to 25°C	Q2 Q1	-20	15		
$\frac{\Delta D_{VDSS}}{\Delta T_J}$	Coefficient	$I_D = -250 \mu A$, referenced to 25°C	Q2		-15		mV/°
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 16V, V _{DS} =0V V _{DS} = -16V, V _{DS} =0V	Q1 Q2			1 -3	μA
I _{GSS}	Gate-Body Leakage	$V_{GS} = \pm 12V, V_{DS} = 0V$ $V_{GS} = \pm 4.5V, V_{DS} = 0V$ $V_{GS} = \pm 8V, V_{DS} = 0V$	Q1 Q1 Q2			±10 ±1 ±10	μA
On Chara	acteristics (note 2)						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\mu A$ $V_{GS} = V_{DS}, I_D = -250\mu A$		0 3	-1.	.j -1.5	v
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250\mu$ A, referenced to 25°C $I_D = -250\mu$ A, referenced to 2 °C	Q'i , 72		-3 ?	N	mV/°(
		$V_{GS} = 4.5V, I_D = 600mA$ $V_{GS} = 2.5V, I_D = 1.5V, I_D = 1.$	Q1	2	0.30 0.40 0.80	0.85	
r _{DS(on)}	Drain to Source On Resistance	$\frac{V_{GS}}{V_{C}} = 4 \frac{7}{5} \frac{1}{J_{D}} \frac{60 \text{ (A, T_{J} - 25^{\circ}C)}}{35 \text{ (A)}}$ $\frac{V_{GS}}{35 \text{ (A)}} = 2 \frac{7}{5} \frac{1}{J_{D}} \frac{1}{35 \text{ (A)}} \frac{1}{35 \text{ (A)}}$	Q2	5	0 0 5 1 0.5 1 0.8	1 2 1.ť	\mathbf{D}^{2}
~	Forward Tennoord	$V_{L} = -1.6$ $V_{D} = -150 \text{ m}^{4}$ $V_{L} = -4.5 \text{ V}, D = -350 \text{ m}^{4}$ $T_{J} = 125^{\circ} \text{ C}$ $V_{L} = 5 \text{ V}, V_{D} = 6.00 \text{ m}^{4}$		2	1.3 0.7 1.8	2.7 1.6	S
9fs	Forward Transcond	V _{DS} = -5V, I ₁ = -3:0mA	Q?)`	1		5
Dynamic	Characte "cs	<u></u>				1	1
C _{iss}	Input C vacitance	Q1 V _{DS} = 10V, V _{GS} = 0V, 1 = 1 MHz	Q1 Q2		60 100		pF
C _{oss}	О Сарилипсе	Q2	Q1 Q2		20 30		pF
	e Transfer Capacitance	V _{DS} = -10V, V _{GS} = 0V, f = 1MHz	Q1 Q2		10 15		pF
Swit in	g Characteristics	1r					
Ն ₍ on)	Tulm-On Delay Time	Q1 V _{DD} = 10V, I _D = 1A,	Q1 Q2		6 6	12 12	ns
, Ч	Rise Time	V_{GS} = 4.5V, R_g = 6 Ω	Q1 Q2		8 13	16 23	ns
t _{d(off)}	Turn Of Delay Time	Q2 V _{DD} = -10V, I _D = -0.5A,	Q1 Q2		8 8	16 16	ns
t _f	Fall Time	V_{GS}^{D} = -4.5V, R_{g} = 6 Ω	Q1 Q2		2.4 1	4.8 2	ns
Qg	Total Gate Charge	Q1	Q1 Q2		0.8 1.0	1.1 1.4	nC
Q _{gs}	Gate to Source Gate Charge	V _{DS} = 10V, I _D = 600mA, V _{GS} = 4.5V	Q1 Q2		0.16	1.4	nC
Q _{gd}	Gate to Drain "Miller"Charge	Q2 V _{DS} = -10V, I _D = -350mA, V _{GS} = -4.5V	Q1		0.26		nC
90			Q2		0.3		

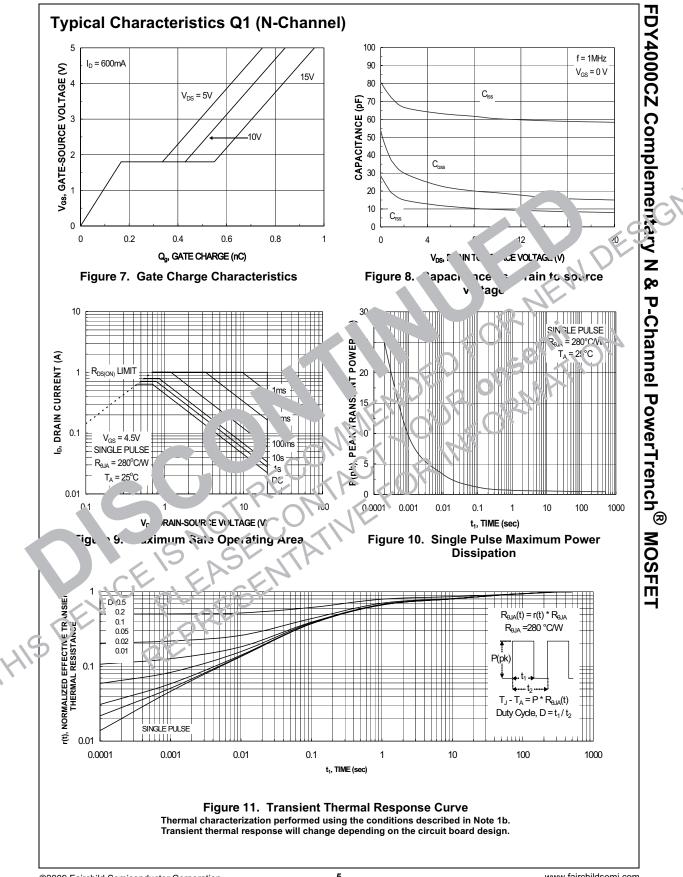
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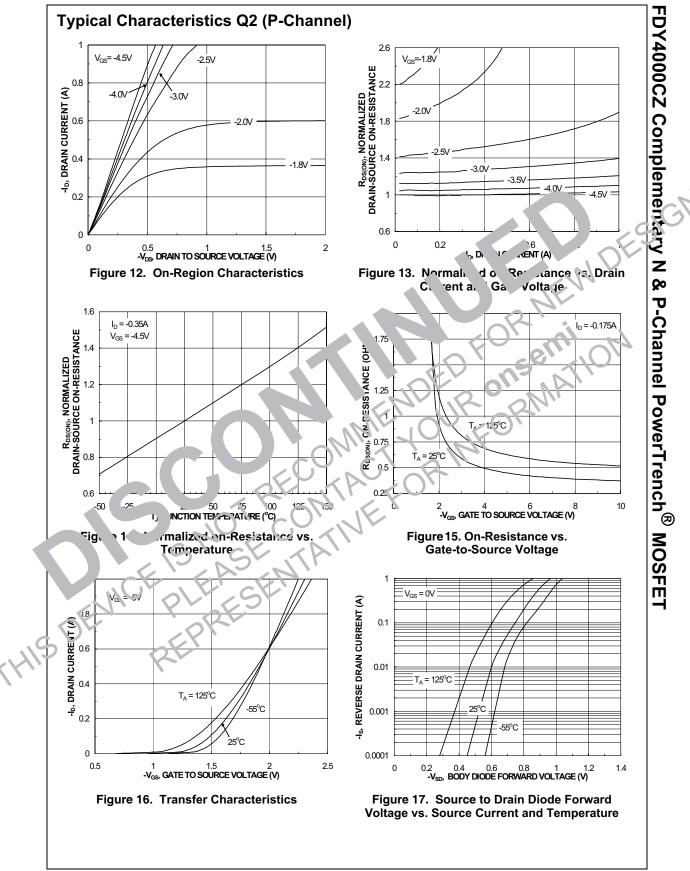




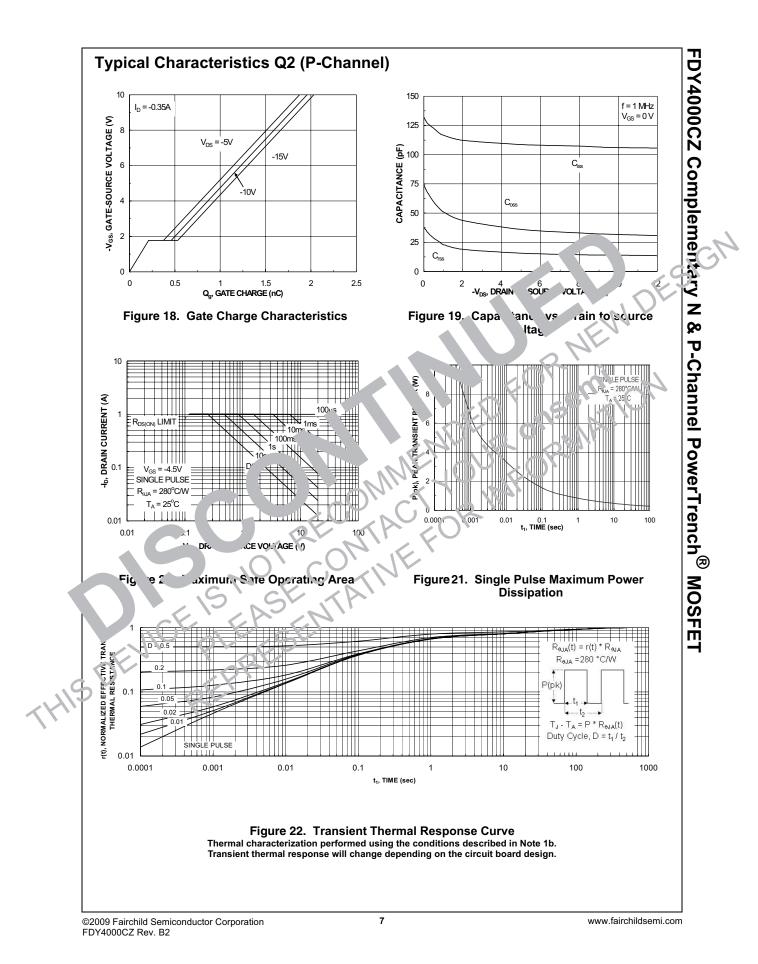
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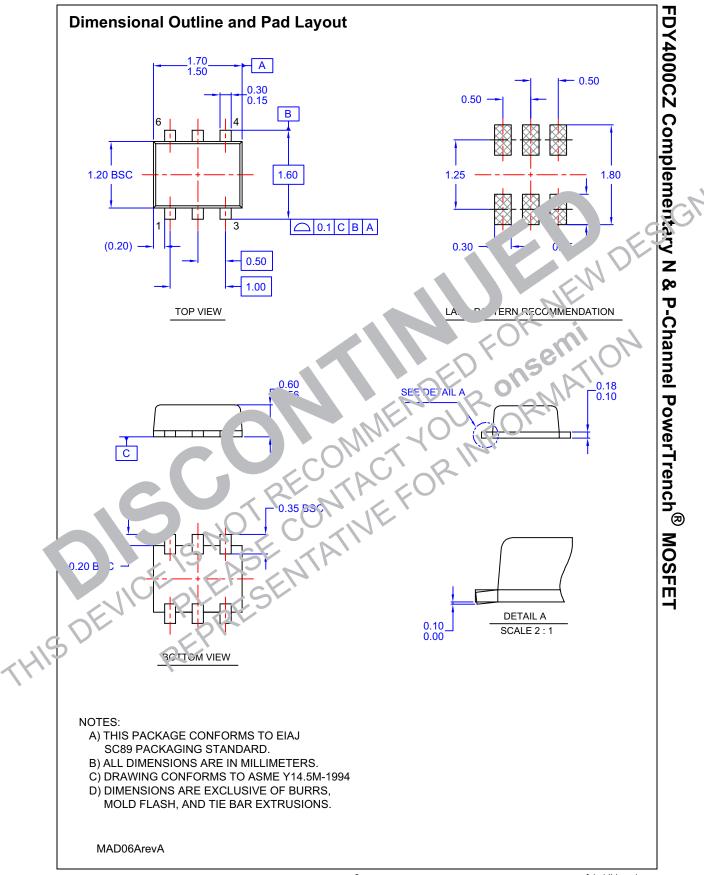
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Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
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No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.		
Obsolete	Not In Production Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.			
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